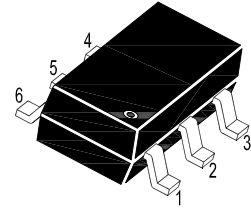
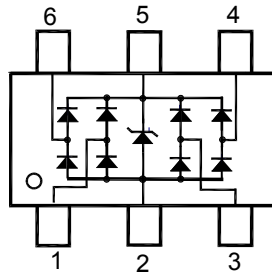


# ESDLC4201D

## ESD Protection Diode



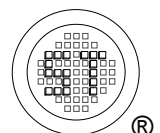
1. I/O1 2. GND 3. I/O2  
4. I/O3 5. V<sub>CC</sub> 6. I/O4  
Marking Code: **63M**  
SOT-26 Plastic package

### Absolute Maximum Ratings (T<sub>a</sub> = 25°C)

Parameter	Symbol	Value	Unit
Peak Power Dissipation (tp = 8/20 μs)	P <sub>PK</sub>	500	W
Peak Pulse Current (tp = 8/20 μs)	I <sub>PP</sub>	25	A
ESD per IEC 61000-4-2 (Air) ESD per IEC 61000-4-2 (Contact)	V <sub>PP</sub>	20 20	KV
IEC 61000-4-4 (5/50 ns)	EFT	40	A
Operating junction Temperature Range	T <sub>j</sub>	- 40 to + 125	°C
Storage Temperature Range	T <sub>stg</sub>	- 55 to + 150	°C

### Characteristics at T<sub>a</sub> = 25°C

Parameter	Symbol	Min.	Max.	Unit
Reverse Voltage at Pin 5 to 2	V <sub>RWM</sub>	-	5	V
Reverse Breakdown Voltage at I <sub>T</sub> = 1 mA	V <sub>BR</sub>	6	-	V
Leakaeg Current at V <sub>R</sub> = 5 V	I <sub>R</sub>	-	5	μA
Clamping Voltage at I <sub>PP</sub> = 5 A, tp = 8/20 μs, Pin 5 to Pin 2 at I <sub>PP</sub> = 8 A, tp = 8/20 μs, Pin 5 to Pin 2 at I <sub>PP</sub> = 25 A, tp = 8/20 μs, Pin 5 to Pin 2	V <sub>C</sub>	- - -	11 12 20	V
Junction Capacitance at V <sub>R</sub> = 0 V, f = 1 MHz, Between I/O Pins to GND at V <sub>R</sub> = 0 V, f = 1 MHz, Between I/O Pins	C <sub>j</sub>	- -	5 3	pF



# ESDLC4201D

## Electrical characteristic curves

Fig 1. Pulse Waveform

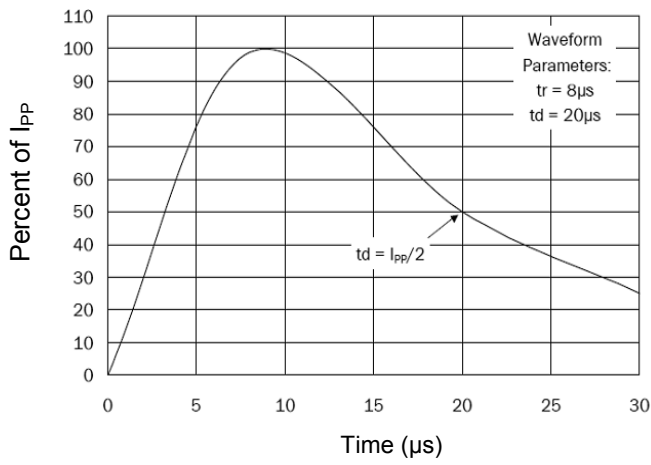


Fig 2. Power Derating Curve

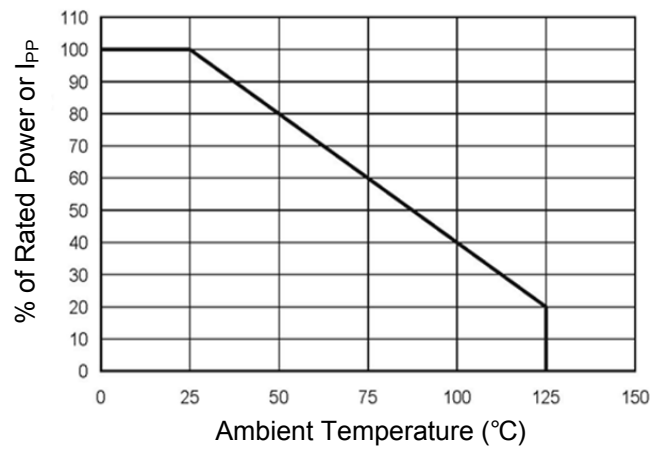


Fig 3. Clamping Voltage Curve

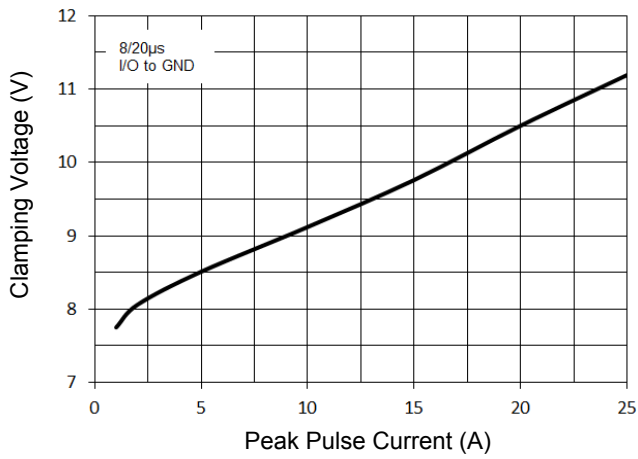


Fig 4. Junction Capacitance

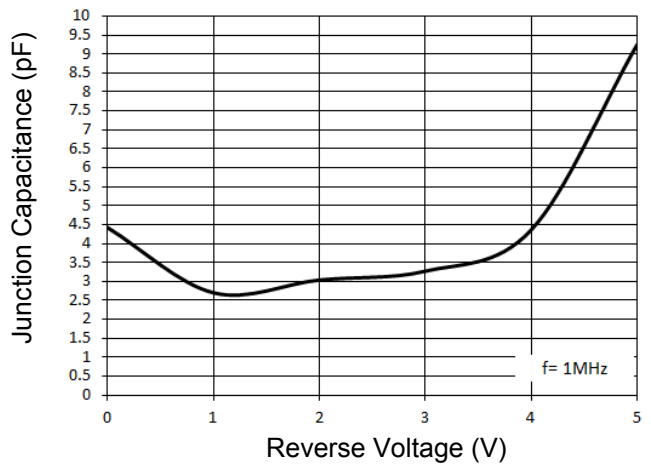
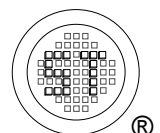
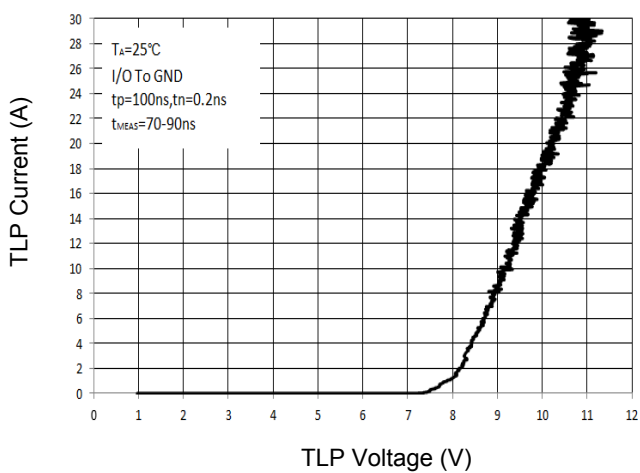


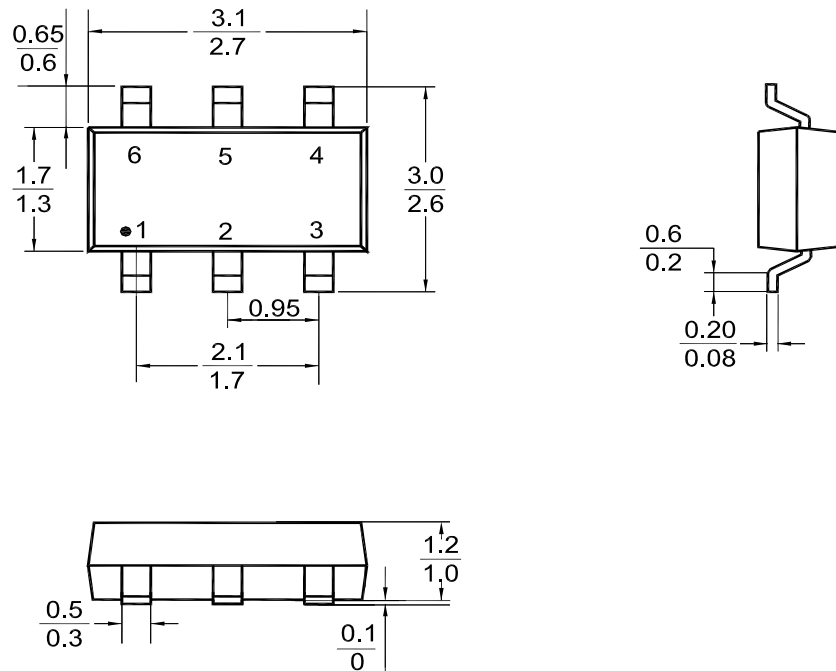
Fig 5. TLP Curve



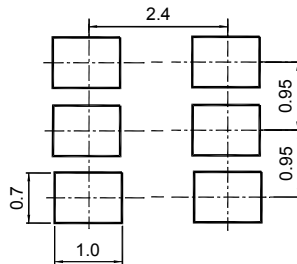
# ESDLC4201D

## Package Outline Dimensions (Units: mm)

SOT-26



## Recommended Soldering Footprint



## Packing information

Package	Tape Width (mm)	Pitch		Reel Size		Per Reel Packing Quantity
		mm	inch	mm	inch	
SOT-26	8	4 ± 0.1	0.157 ± 0.004	178	7	3,000

## Marking information

- "63M" = Part No.
- "YM" = Date Code Marking
- "Y" = Year
- "M" = Month
- Font type: Arial

